

RoHS

COMPLIANT

HALOGEN FREE Available

**Vishay Siliconix** 

# P-Channel 12-V (D-S) MOSFET

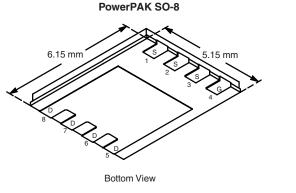
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)		
	0.0065 at V <sub>GS</sub> = - 4.5 V	- 21		
- 12	0.008 at V <sub>GS</sub> = - 2.5 V	- 19		
	0.011 at V <sub>GS</sub> = - 1.8V	- 16		

#### **FEATURES**

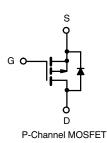
- Halogen-free According to IEC 61249-2-21
  Available
- TrenchFET<sup>®</sup> Power MOSFET
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package with Low 1.07 mm Profile

#### **APPLICATIONS**

Load Switch



Ordering Information: Si7495DP-T1-E3 (Lead (Pb)-free) Si7495DP-T1-GE3 (Lead (Pb)-free and Halogen-free)



<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unles	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 12		V
Gate-Source Voltage		V <sub>GS</sub>	± 8		
Continuous Drain Current (T 150 °C)	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 21	- 13	٨
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		- 17	- 10	
Pulsed Drain Current		I <sub>DM</sub>	- 50		A
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	- 4.5	- 1.6	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	5	1.8	W
	T <sub>A</sub> = 70 °C		3.2	1.1	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>			260		C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lumation to Ambianta	t ≤ 10 s	R <sub>thJA</sub>	20	25	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		54	68	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	1.7	2.2	

Notes

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

# Vishay Siliconix



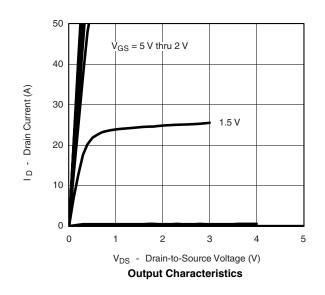
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static				•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{GS(th)}$ $V_{DS} = V_{GS}$ , $I_D = -1$ mA			- 0.9	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -12 V, V_{GS} = 0 V$			- 1	μA	
		$V_{DS}$ = - 12 V, $V_{GS}$ = 0 V, $T_{J}$ = 70 °C			-10		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS}{\leq}$ - 5 V, $V_{GS}$ = - 4.5 V	- 40			А	
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 21 A		0.0054	0.0065		
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 19 A		0.0065	0.008	Ω	
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 16 A		0.0088	0.011		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 21 A		80		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{\rm S}$ = - 4.5 A, $V_{\rm GS}$ = 0 V		- 0.65	- 1.1	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			93	140		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -6 V$ , $V_{GS} = -5 V$ , $I_{D} = -21 A$		10.5		nC	
Gate-Drain Charge	Q <sub>gd</sub>			22			
Gate Resistance	Rg			2.7		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			100	150		
Rise Time	tr	$V_{DD}$ = - 6 V, $R_L$ = 6 $\Omega$		200	300	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ - 1 A, $V_{GEN}$ = - 4.5 V, $R_g$ = 6 $\Omega$		350	530		
Fall Time	t <sub>f</sub>			230	350		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 2.9 A, dl/dt = 100 A/μs		110	165		

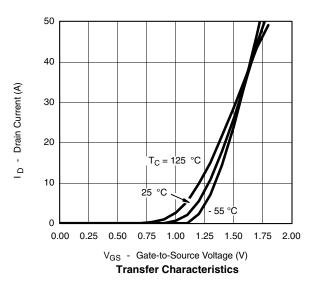
Notes:

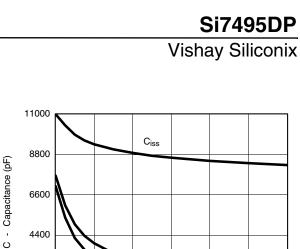
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless noted







6600

4400

2200

0

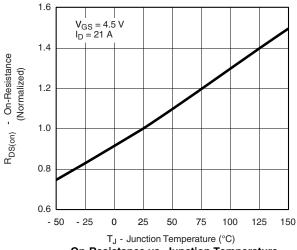
0

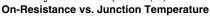
Crss

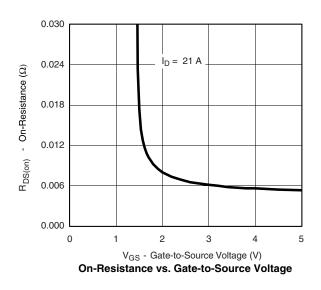


 $C_{\text{oss}}$ 

12

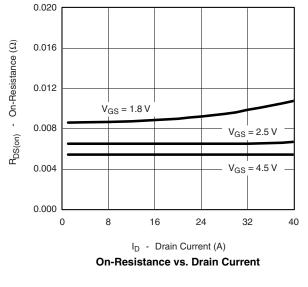


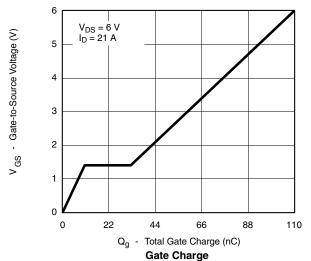


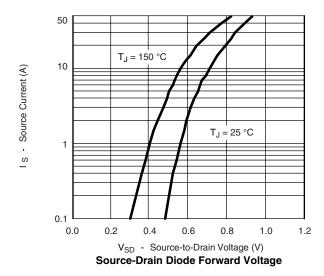




VISHAY



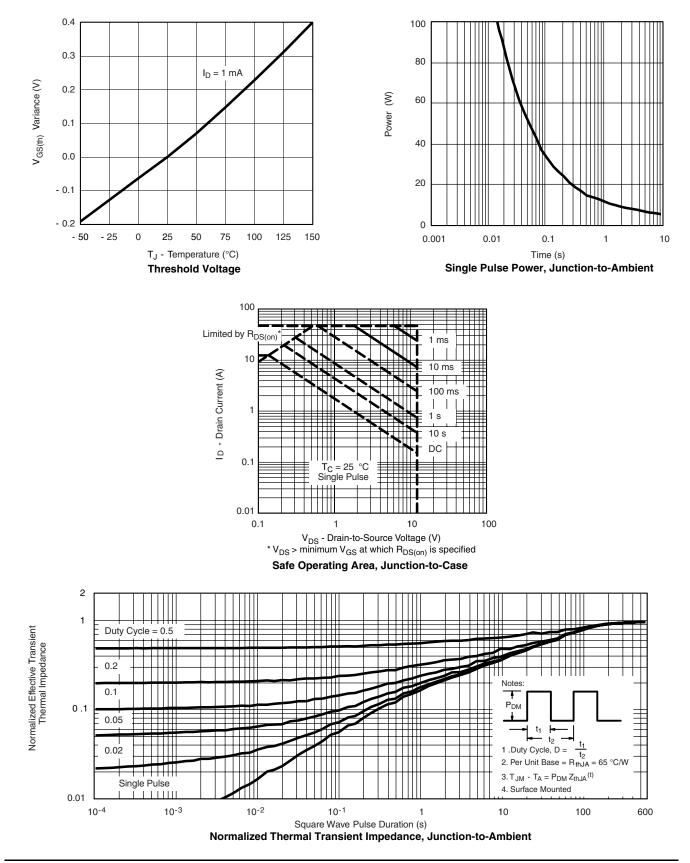




Document Number: 72277 S09-0268-Rev. C, 16-Feb-09

### **Vishay Siliconix**

#### TYPICAL CHARACTERISTICS 25 °C, unless noted

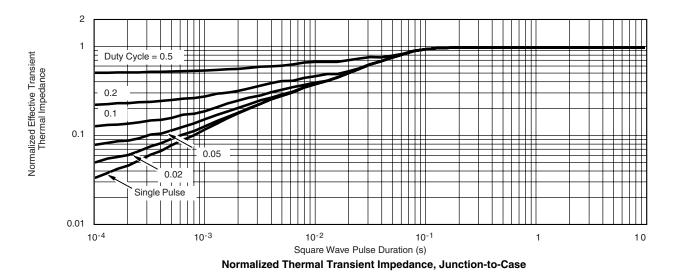






Si7495DP Vishay Siliconix

### TYPICAL CHARACTERISTICS 25 °C, unless noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?72277</u>.



Vishay

### Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.